Middle Power LED PLCC Series

o.2W White SPMWHT3235A3



Features

- Package : Au Plated 2 pad design package with silicone resin
- Dimension : 3.2 mm x 2.8 mm
- Technology : Epi-up
- Color Coordinate Group : Appropriate to ECE
- Chip Configuration : 1 chip
- ESD Voltage : Up to 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 3B)
- Viewing Angle: 120°
- Qualifications: The product qualification test based on the guidelines of AEC-Q101-REV-C.

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1. Characteristics

a) Typical Characteristics

ltem	Symbol	Value	Unit.
Luminous Flux (I _F = 50 mA)	Iv	Тур. 3.5	cd
Forward Voltage (I _F = 50 mA)	VF	Тур. 3.1	V
Viewing Angle	φ	Тур. 120	o
Reverse Current	I _R	10	μA
Real Thermal Resistance	D	Тур. 77	12001
(Junction to Solder point)	R _{th_J-S} (Real)	Max. 90	K/W
Electrical Thermal Resistance	D	Тур. 60	
(Junction to Solder point)	R _{th_J-S} (Elec.)	Max. 70	K/W
Radian Surface	А	4.52	mm ²
Note:			

[1] The measurement condition means that temperature dependence is excluded by applying pulse current for typically 25ms.

b) Absolute Maximum Rating

ltem	Symbol	Rating	Unit
Ambient / Operating Temperature	Ta	-40 ~ +110	٥C
Storage Temperature	T _{stg}	-40 ~ +110	٥C
LED Junction Temperature	Tj	125	٥C
Maximum Forward current ^[2] (T _j : 25°C) ^[3]	l _F	70	mA
Minimum Forward current ^[2] (Tj: 25°C) ^[3]	l _F	10	mA
Maximum Reverse current		Do not apply for reverse current	
ESD Sensitivity ^[4]	-	±2 HBM	kV
Note:			

[2] Driving the product at forward current (IF) below Min. IF or above Max. IF may result in unpredictable behavior of the product.

[3] The measurement condition means that temperature dependence is excluded by applying pulse current for typically 25ms.

[4] It is recommended to use the LED with additional protection device (for example Zener diode) to protect it against ESD.

 $[T_j=25^{\circ}C]^{[1]}$

2. Product Code Information

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S	Р	М	W	н	Т	3	2	3	5	Α	3	Α	В	С	D	E	F
Di	git							Ρ	'KG Info	ormatio	n						
1	2	comp	company name and Samsung LED PKG (SP for Samsung PKG)														
3		power	⁻ variar	nt (M fo	r auton	notive r	niddle	power))								
4	5	color	variant	t (WH fo	or auto	motive	white	color)									
6		LED F	PKG ve	ersion (T for in	itial vei	sion)										
7	89	produ	product configuration and type (323 for automotive 3228 PKG Au plate type)														
10		opera	ating co	ondition	(5 for	50mA)											
11		speci	specific property (A for Automotive)														
12		CRI V	CRI Variant (3 for CRI Min. 70)														
13	14	forwa	forward voltage property														
15	16	CIE c	CIE coordination property														
17	18	lumin	ous flu	x prope	erty												



a) Luminous Intensity Bins $^{[5]}(I_{\text{F}}\text{=}50\text{ mA},\,T_{\text{j}}\text{=}25\text{ °C})$

Cumbol	Bin Code	Intensity I	Range (cd)	Flux Range (lm)		
Symbol	Bin Code	Min	Max	Min	Max	
1.1.0	A2	3.0	4.0	9.0	12.0	
$I_V \mid \Phi_V$	A3	4.0	5.0	12.0	15.0	

b) Voltage Bins ^[5] (I_F= 50 mA, T_j= 25 °C)

Symbol	Bin Code	Voltage Range (V)			
Symbol	Directee	Min	Max		
	C1	2.7	3.0		
VF	C2	3.0	3.3		
	C3	3.3	3.6		

Note:

[5] Luminous intensity measuring equipment: CAS140CT

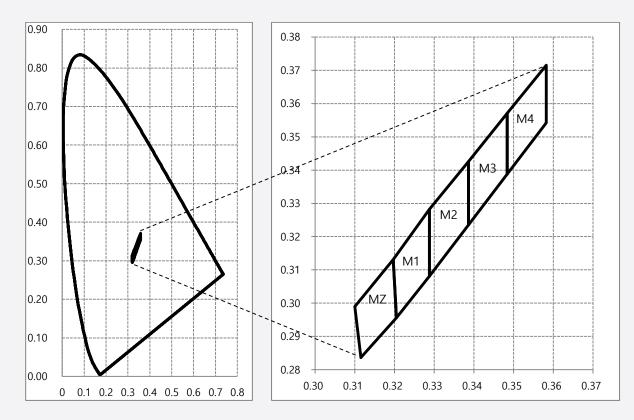
 Φ_V and V_F tolerances are ±7% and ±0.1V, respectively.

c) Color Bins $^{[6]}$ (I_F= 50 mA)

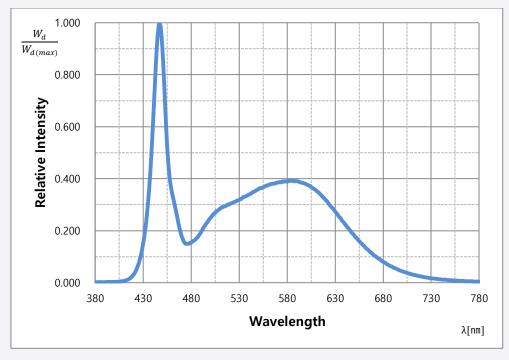
Symbol	Bin Code		С	×			C	•У	
	MZ	0.3115	0.3205	0.3197	0.3100	0.2837	0.2956	0.3131	0.2990
	M1	0.3205	0.3197	0.3288	0.3288	0.2956	0.3131	0.3282	0.3081
C _x , C _y	M2	0.3288	0.3288	0.3386	0.3386	0.3081	0.3282	0.3426	0.3235
	M3	0.3386	0.3386	0.3484	0.3484	0.3235	0.3426	0.3571	0.3388
	M4	0.3484	0.3484	0.3582	0.3582	0.3388	0.3571	0.3715	0.3542

Note

[6] Chromaticity coordinates: C_x , C_y according to CIE 1931. C_x and C_y tolerances are ±0.005, respectively.

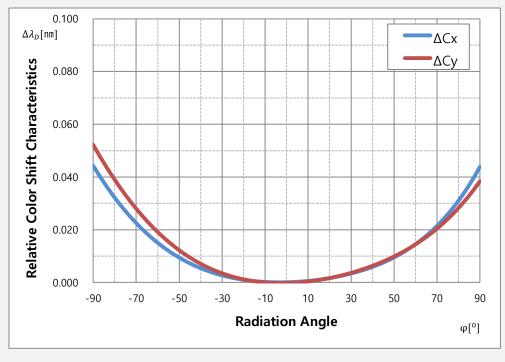


3. Typical Characteristics Graphs



a) Spectrum Distribution (I_F= 50 mA, T_s= 25 °C)^[7]

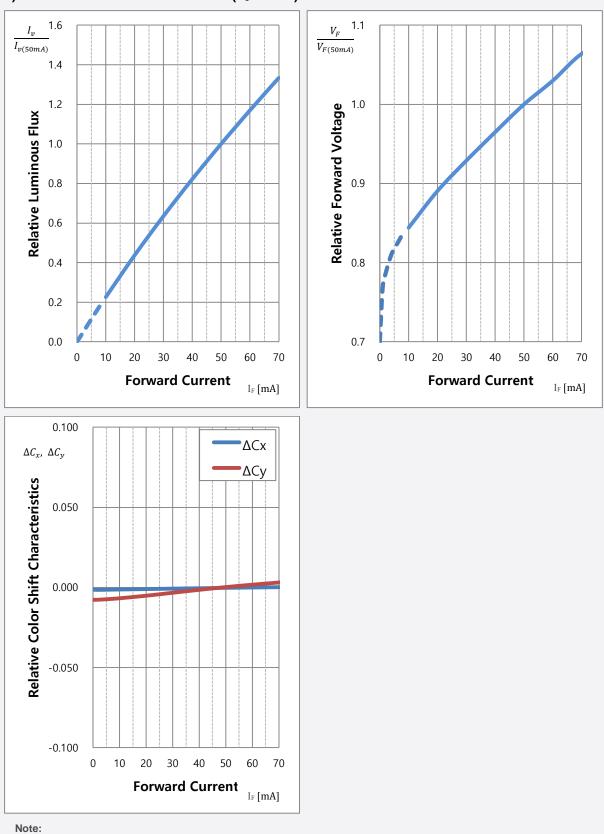
b) Typical Chromaticity Coordinate Shift vs Radiation Angle (I_F = 50 mA, T_s = 25 °C)^[7]



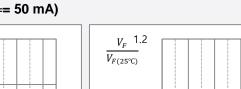
Note:

[7] The measurement condition means that temperature dependence is excluded by applying pulse current for typically 25ms.

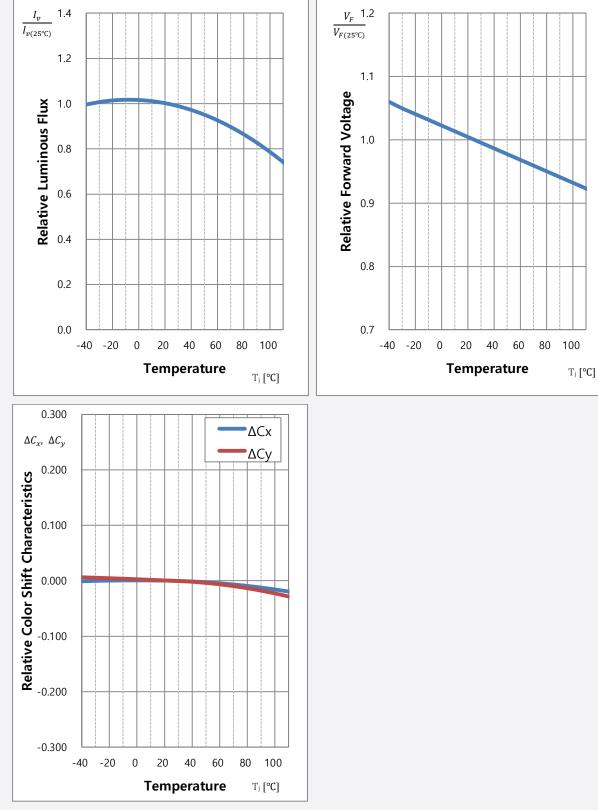
c) Forward Current Characteristics (T_s= 25 $^{\circ}$ C)^[8]



[8] The measurement condition means that temperature dependence is excluded by applying pulse current for typically 25ms.

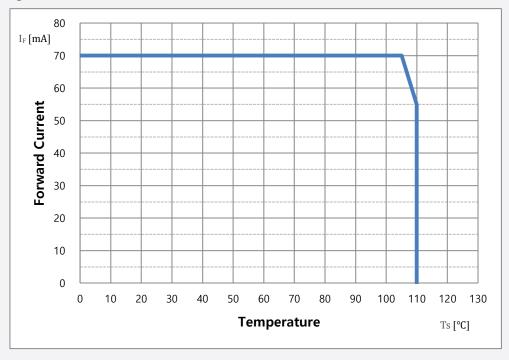


d) Temperature Characteristics (I_F= 50 mA)



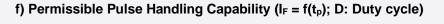


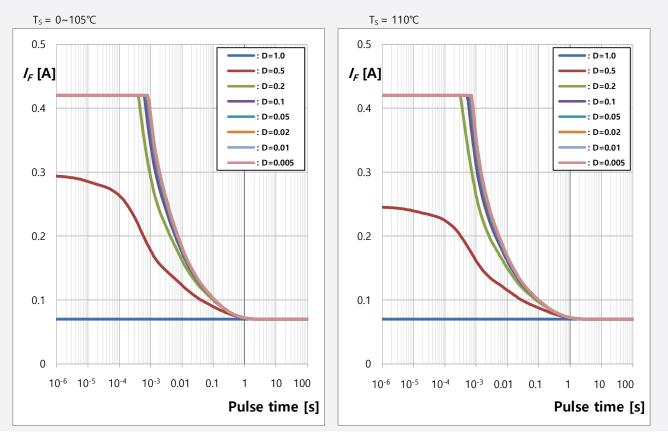
e) Derating Curve ^[9]



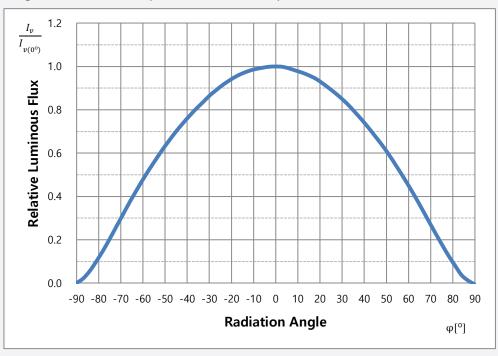
Notes:

[9] The measurement condition means that temperature dependence is excluded by applying pulse current for typically 25ms.



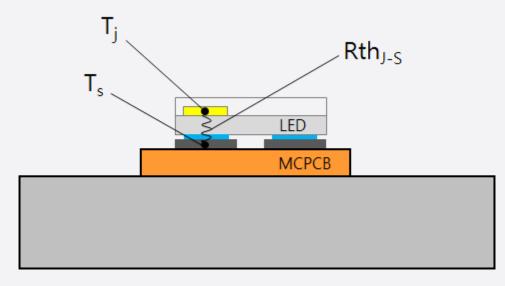


g) Beam Angle Characteristics (I_F= 50 mA, T_s= 25 °C)





4. Soldering Temperature Location

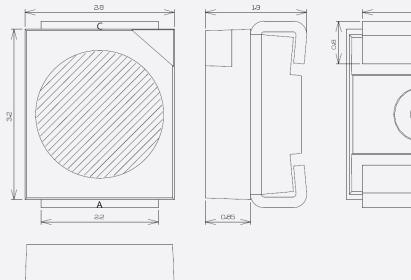


T_j: Temperature of Junction

T_s: Temperature of Solder Pad

 $R_{\text{th}_J\text{-}S}$: Thermal Resistance from Junction to Solder Pad

5. Mechanical Dimension



2.2



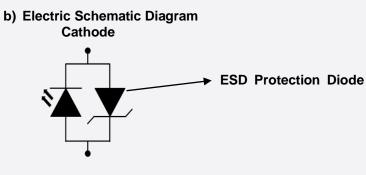
Note:

Unit: mm, Tolerance: ±0.1mm, Approximate Weight : 36mg, A: Anode, C: Cathode

a) Pick and Place

Do not place pressure on the resin lens (hatch area).

The maximum compressing force is 15N in the polymer.



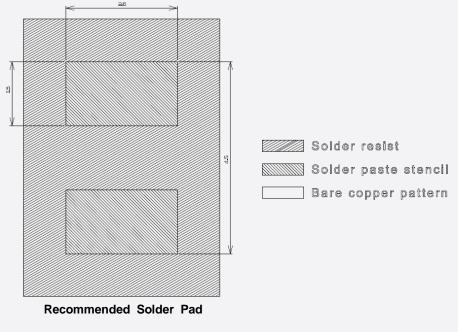
[Circuit]

c) Material Information

Description	Material
Lead flame	PLCC
LED Die	Epi-up
Wire	Au
Resin Mold	Silicone

6. Soldering Conditions

a) Pad Configuration & Solder Pad Layout

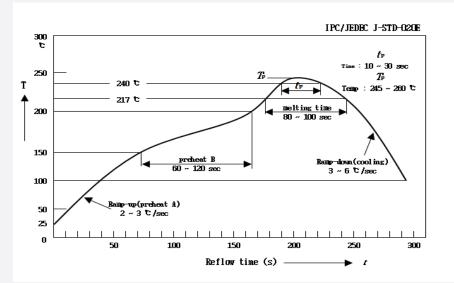


Notes:

Unit: mm, Tolerance: ±0.1mm

b) Reflow Conditions (Pb free)

Reflow frequency: 2 times max.

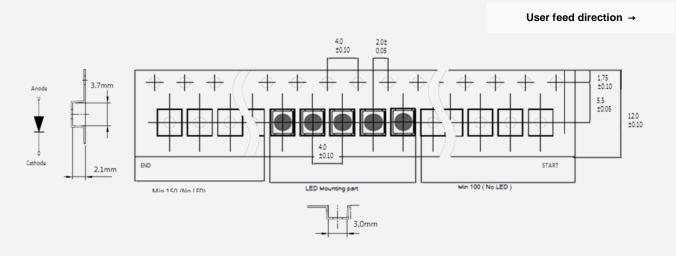


c) Manual Soldering Conditions

Not more than 5 seconds @ max 300 °C, under soldering iron. (One time only)

7. Tape & Reel

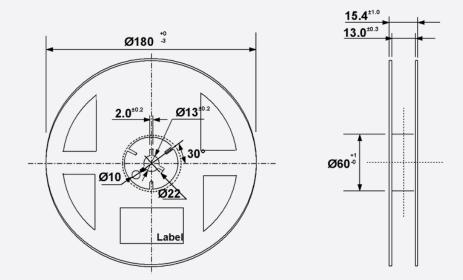
a) Taping Dimension



Note:

Unit: mm, LED taping quantity: 2,000EA / Reel

b) Reel Dimension



Notes:

Unit: mm, Tolerance: ±0.2mm

8. Label Structure

a) Product Labeling Information



N.B) Denoted rank is the only example.

b) Bin Code Structure

AB: Forward Voltage (V_F) Bin (refer to page. 5) CD: Color bin (C_x, C_y) (refer to page. 6) EF: Luminous Flux (I_v) Bin (refer to page. 5)

c) Lot Number Structure

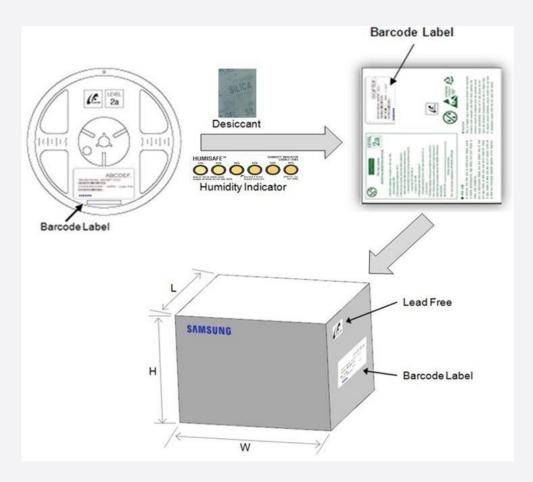
The lot number is composed of the following characters:

No.	Information
1	Production Site : S:SAMSUNG LED, G:GOSIN CHINA
2	LED
3	Product State A :Normality, B :Bulk, C :First Production, R :Reproduction, S :Sample
4	Year : Y:2014, Z:2015, A:2016, B:2017, C:2018
5	Month : 1 ~ 9, A, B
6	Day : 1 ~ 9, A, B ~ V
789	Product number : 1 ~ 999
abc	Reel Number : 1 ~ 999



9. Packing Structure

a) Packing Process



Dimension of Transportation Box in mm

Width	Length	Height
220	245	182



10. Handling and use precautions

- 1) For over-current protection, we recommend the use of resistors to prevent sudden current surges caused by slight shifts in voltage
- 2) LEDs should not be contacted to any type of fluid (i.e. water, oil, organic solvent, etc.). If cleaning is required, only use isopropyl alcohol.
- 3) The maximum ambient temperature must be considered in order for the maximum temperature ratings not to be exceeded.
- 4) LEDs must be stored in a clean environment. If the LEDs are to be stored for 3 months or more after being shipped from Samsung Electronics, they should be packed by a sealed container with nitrogen gas injected. (Shelf life of sealed bags: 12 months, temp. ~40°C, ~90% RH)
- 5) After storage bag is open, LED subjected to soldering, solder reflow, or other high temperature processes must be:
 - a) Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30°C / 60% RH.
 - b) Stored at <10% RH.
- Repack unused products using anti-moisture packing, fold to close any openings and store in a dry place with <10% RH.
- 7) LEDs require baking before mounting, if humidity card reading is >60% at $23\pm5^{\circ}$ C.
- 8) If baking is required, LEDs must be baked for 1 day at 60±5℃.
- 9) LEDs are sensitive to electrostatic discharge and surges. Applying any voltage exceeding the absolute maximum rating of the LED can cause permanent damage to the device. Damaged LEDs may have some unusual characteristics such as increased leakage current, lower turn-on voltage or may light abnormally at low current. When handling LEDs, using grounding wristbands or anti-static gloves is recommended.
- 10) VOCs (volatile organic compounds) present in adhesives, flux, hardeners or organic additives, etc. that are used in luminaires may lead to discoloration of the LED when exposed to heat or light. Note that VOCs can permeate silicone bags. This phenomenon can significantly affect light output from the luminaire. To avoid this issue, please carefully evaluate materials used in your process and/or luminaire to be free of VOCs.
- 11) To avoid risk of sulfurization (or tarnishing), do not use or store LEDs near materials containing sulfur, fluorine, chlorine, bromine, iodine or other halogens or compounds that can potentially react with the LED's silver plated lead frame. Examples of these materials include: various rubbers, paper products, certain solder pastes, cleaning solutions, adhesives, etc. or may be present in certain environments in form of fertilizers, lubricants, etc. This reaction can result into the lead frame darkening when exposed to such compounds, resulting in degradation of intensity, change in forward voltage, chromaticity coordinate shift and it may go as far as becoming an open circuit in more extreme cases.

11. Company Information

SAMSUNG

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